



### DMNH10H028SPSQ

# 100V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>C</sub> = +25°C
100V	$28m\Omega @ V_{GS} = 10V$	40A

### **Features**

- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications</li>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

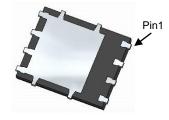
#### **Mechanical Data**

- Case: POWERDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

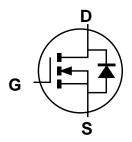




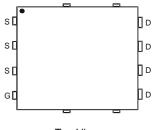
Top View



**Bottom View** 



Internal Schematic



Top View Pin Configuration

### Ordering Information (Note 5)

Part Number	Case	Packaging
DMNH10H028SPSQ-13	POWERDI®5060-8	2500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. For more information, please refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



DII=Manufacturer's Marking
H1H28SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 15 = 2015)
WW = Week Code (01 to 53)

POWERDI is a registered trademark of Diodes Incorporated.

DMNH10H028SPSQ
Document number: DS38226 Rev. 1 - 2



### **Maximum Ratings** (@T<sub>C</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			$V_{DSS}$	100	V
Gate-Source Voltage			$V_{GSS}$	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V	I <sub>D</sub>	40 25	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) (Note 6)			I <sub>DM</sub>	54	Α
Maximum Continuous Body Diode Forward Current (Note 7)			Is	3.9	Α
Avalanche Current (Note 9) L=0.1mH			I <sub>AS</sub>	26	Α
Avalanche Energy (Note 9) L=0.1mH			E <sub>AS</sub>	35	mJ

### **Thermal Characteristics**

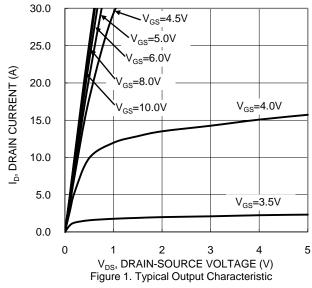
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		$P_D$	1.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	$R_{ heta JA}$	97	°C/W
Total Power Dissipation (Note 7)		$P_D$	2.9	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady state	$R_{ heta JA}$	52	°C/W
Thermal Resistance, Junction to Case		$R_{ heta JC}$	1.8	C/VV
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

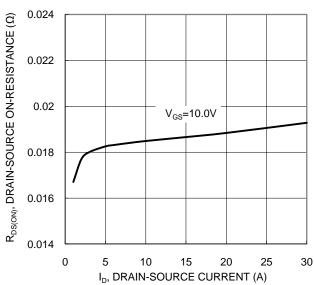
# **Electrical Characteristics** (@ $T_C = +25$ °C, unless otherwise specified.)

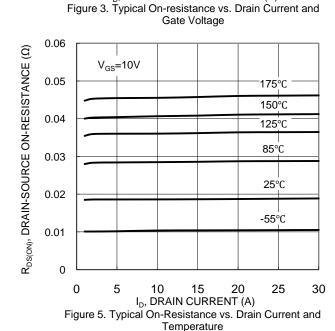
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1.0	μΑ	$V_{DS} = 100V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2.0	2.5	4.0	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	19	28	mΩ	$V_{GS} = 10V, I_D = 20A$
Diode Forward Voltage	$V_{SD}$	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1.0A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	_	2245	_		V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V f = 1.0MHz
Output Capacitance	Coss	_	173		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	68	_		
Gate Resistance	R <sub>G</sub>	_	1.9		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$	_	36	_		
Total Gate Charge (V <sub>GS</sub> = 6.0V)	$Q_g$	_	22	_	nC	$V_{DD} = 50V, I_D = 20A$
Gate-Source Charge	$Q_{gs}$	_	7.3	_	IIC	
Gate-Drain Charge	$Q_{gd}$	_	9.2	_		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.4	_		$V_{GS} = 10V, V_{DS} = 50V,$ $R_G = 3.0\Omega, I_D = 20A$
Turn-On Rise Time	t <sub>R</sub>	_	5.8	_	20	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	17.8	_	ns	
Turn-Off Fall Time	t <sub>F</sub>	_	4.8	_		
Reverse Recovery Time	t <sub>RR</sub>	_	35	_	ns	I <sub>F</sub> = 20A, di/dt = 100A/μs
Reverse Recovery Charge	Q <sub>RR</sub>	_	47	_	nC	I <sub>F</sub> = 20A, di/dt = 100A/µs

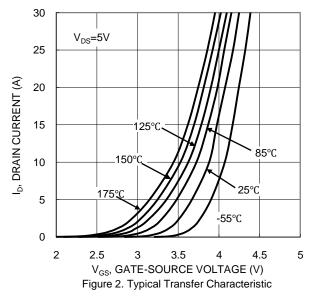
6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing. Notes:

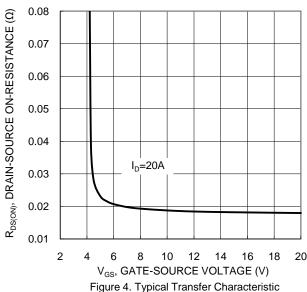












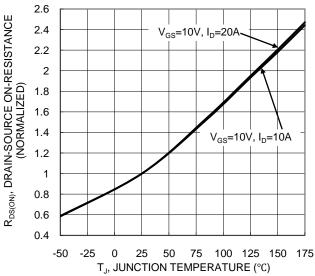


Figure 6. On-Resistance Variation with Temperature

### DMNH10H028SPSQ

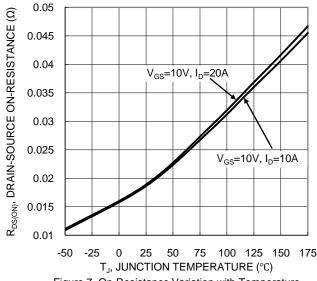
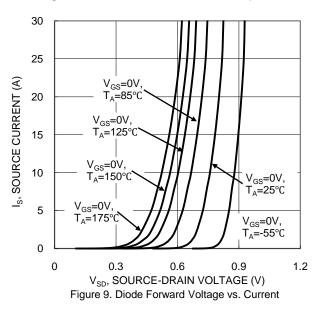
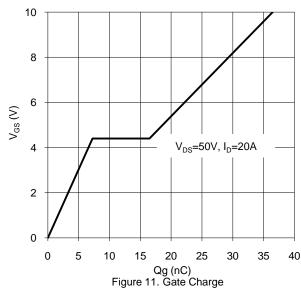


Figure 7. On-Resistance Variation with Temperature





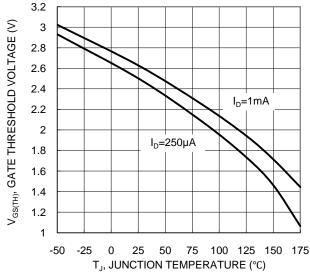
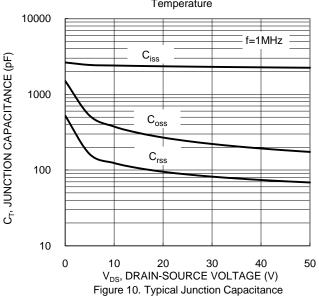
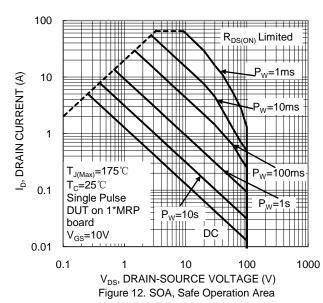


Figure 8. Gate Threshold Variation vs. Junction
Temperature







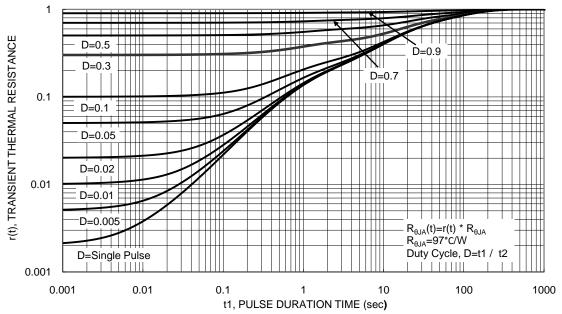


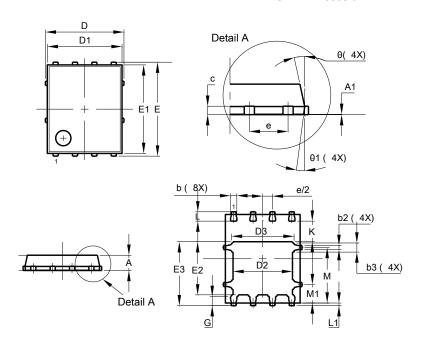
Figure 13. Transient Thermal Resistance



### **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### POWERDI®5060-8

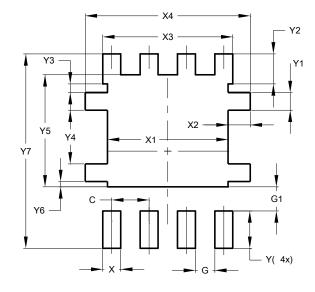


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POWERDI®5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	,	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(	6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	-	_		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
M	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12º	11º		
Θ1	6º	8º	7º		
All	All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### POWERDI®5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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